

HTS16A60H/HTS16A80H 3 Quadrants Standard TRIAC

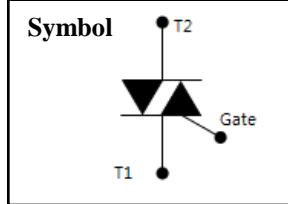
FEATURES

- Repetitive Peak Off-State Voltage : 600V/800V
- R.M.S On-State Current ($I_{T(RMS)} = 16A$)
- Gate Trigger Current : 35mA
- High commutation capability.

Applications

General purpose of AC switching, heating control, motor control, etc

| |
|-----------------------|
| $V_{DRM} = 600V/800V$ |
| $I_{T(RMS)} = 16 A$ |
| $I_{TSM} = 168 A$ |
| $I_{GT} = 35mA$ |



General Description

Semihow's standard TRIAC product is a glass passivated device, has a high commutative performance, stable gate triggering level to temperature and high off state voltage. It is generally suitable for power and phase control in ac application

Absolute Maximum Ratings (T_J=25°C unless otherwise specified)

| Symbol | Parameter | Conditions | Ratings | | Unit |
|--------------|--|---|-----------|-----------|------------|
| | | | HTS16A60H | HTS16A80H | |
| V_{DRM} | Repetitive Peak Off-State Voltage | Sine wave, 50/60Hz, Gate open | 600 | 800 | V |
| V_{RRM} | Repetitive Peak Reverse Voltage | | 600 | 800 | V |
| $I_{T(AV)}$ | Average On-State Current | Full sine wave, $T_C = 81^\circ C$ | 14.4 | | A |
| $I_{T(RMS)}$ | R.M.S. On-State Current | | 16 | | A |
| I_{TSM} | Surge On-State Current | $\frac{1}{2}$ cycle, 50Hz/60Hz, Sine wave, Non repetitive | 160/168 | | A |
| I^2t | Fusing Current | $t = 10ms$ | 128 | | A^2S |
| P_{GM} | Forward Peak Gate Power Dissipation | $T_J = 125^\circ C$ | 5 | | W |
| $P_{G(AV)}$ | Forward Average Gate Power Dissipation | $T_J = 125^\circ C$, over any 20ms | 1 | | W |
| I_{FGM} | Forward Peak Gate Current | $T_J = 125^\circ C$, pulse width $\leq 20\mu s$ | 2 | | A |
| V_{RGM} | Reverse Peak Gate Voltage | $T_J = 125^\circ C$, pulse width $\leq 20\mu s$ | 10 | | V |
| T_J | Operating Junction Temperature | | -40~+150 | | $^\circ C$ |
| T_{STG} | Storage Temperature | | -40~+150 | | $^\circ C$ |

Electrical Characteristics (T_J=25°C unless otherwise specified)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|--|---|-----------------------|-----|-----|-------|
| I _{DRM} | Repetitive Peak Off-State Current | V _D = V _{DRM} | T _J =25°C | - | - | 50 uA |
| | | | T _J =125°C | - | - | 5 mA |
| I _{RRM} | Repetitive Peak Reverse Current | V _D = V _{DRM} | T _J =25°C | - | - | 50 uA |
| | | | T _J =125°C | - | - | 5 mA |
| I _{GT} | Gate Trigger Current | V _D = 12V, R _L =330Ω | 1+, 1-, 3- | - | - | 35 mA |
| V _{GT} | Gate Trigger Voltage | V _D = 12V, R _L =330Ω | 1+, 1-, 3- | - | - | 1.5 V |
| V _{GD} | Non-Trigger Gate Voltage ¹ | V _D = 12V, R _L =330Ω, T _J =125°C | 0.2 | - | - | V |
| V _{TM} | Peak On-State Voltage | I _T = 23A, I _G = 50mA | - | 1.1 | 1.4 | V |
| dv/dt | Critical Rate of Rise of Off-State Voltage | V _D = 2/3 V _{DRM} , T _J =125°C | 200 | - | - | V/us |
| I _H | Holding current | I _T = 0.2A | - | 50 | - | mA |

Notes :

1. Pulse Width ≤ 1.0ms, Duty Cycle ≤ 1%

Thermal Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|--------------------|---------------------|-----|-----|-----|------|
| R _{θJC} | Thermal Resistance | Junction to Case | | | 2.1 | °C/W |
| R _{θJA} | Thermal Resistance | Junction to Ambient | | | 58 | °C/W |

Typical Characteristics

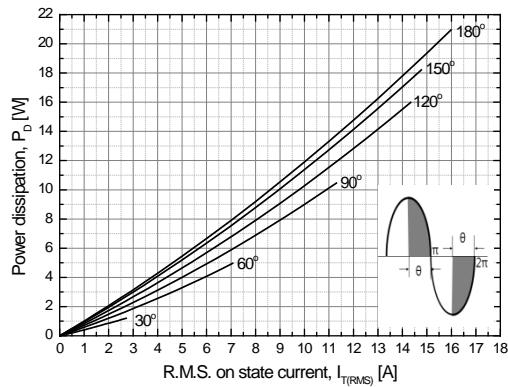


Fig 1. R.M.S. current vs. Power dissipation

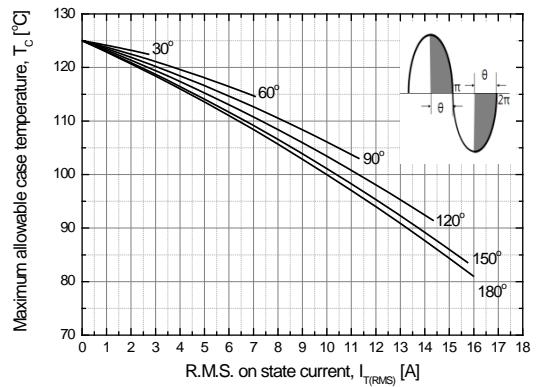


Fig 2. R.M.S. current vs. Case temperature

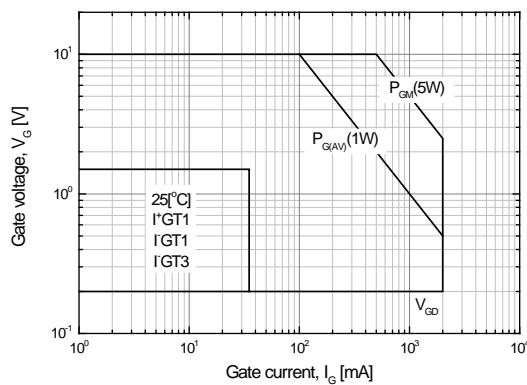
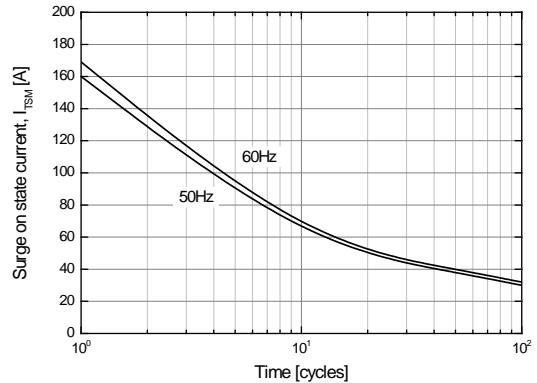
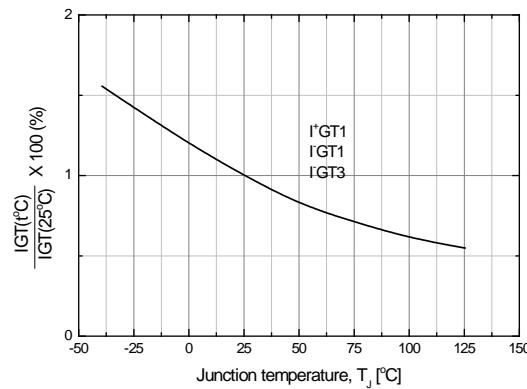


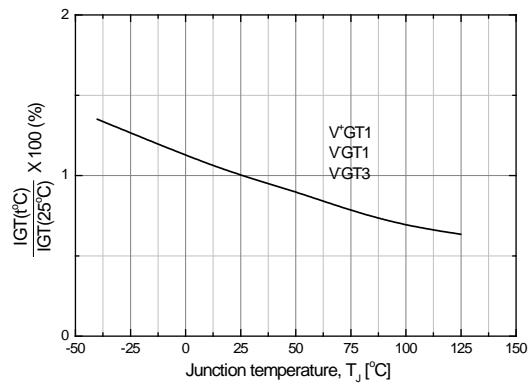
Fig 3. Gate power characteristics



**Fig 4. Surge on state current rating
(Non-repetitive)**

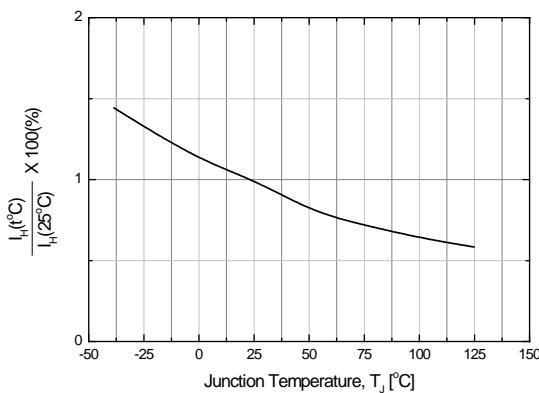


**Fig 5. Gate trigger current vs.
junction temperature**



**Fig 6. Gate trigger voltage vs.
junction temperature**

Typical Characteristics



**Fig 7. Holding current vs.
Junction temperature**

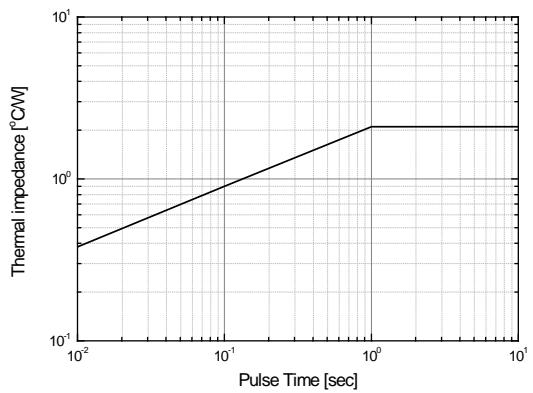
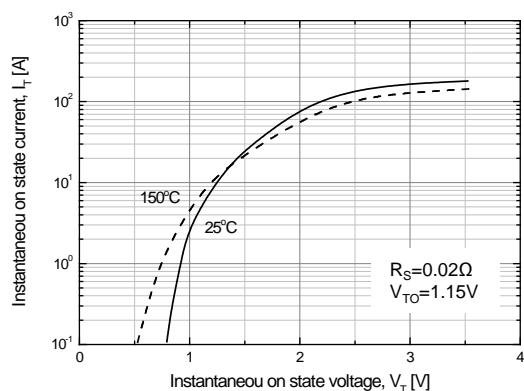
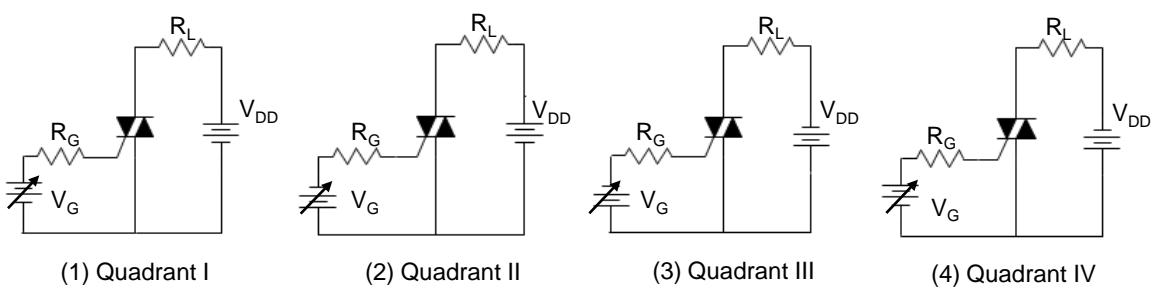


Fig 8. Thermal Impedance vs. pulse time



**Fig 9. Instantaneous on state current vs.
Instantaneous on state voltage**

Measurement of gate trigger current



Note. Whole parameter and test condition can not be over absolute maximum ratings in this datasheet.

Package Dimension**TO-220F**